

Sunday

Monday

Tuesday

Wednesday

Thursday

Registration 8:00–8:45

Welcome
8:45

Amano
9:00–9:45

Redwing
9:45–10:30

Coffee break 10:30–11:00

Microscopic
Studies
of GaN
and InGaN
11:00–12:30

Antimonides
and Other
Materials
11:00–12:30

Lunch
12:30–13:25

Han
13:25

InGaN
Quantum
Wells
14:00–15:00

Growth on
Si and SOI
14:00–15:00

Coffee break 15:00–15:25

Schmid
15:25

Micro-LEDs
16:00–17:30

Quantum
Dots
16:00–17:30

Registration
14:30–18:00

Welcome
reception
18:00–21:00

Registration
8:00–9:00

Geisz
9:00–9:45

Struc.Stud.of
GaN & Rel.
9:50–10:35

Nanostruc-
tures on Si
9:50–10:35

Davies
11:00

Non-Polar
Growth
and Rel.
11:35–12:35

Solar Cells
and Rel.
Basics
11:35–12:35

Sugiyama
13:30

AlN and
AlGaIn
14:05–15:05

InP- and
GaAs-based
Structures
14:05–15:05

Coffee break 15:05–15:25

Poster session 1
15:30–17:30

Duchemin
18:00–18:45

Heuken
18:45–19:30

Haberland
19:45–20:30

Registration
8:00–9:00

Thelander
9:00–9:45

Doping of
Nitrides
9:50–10:35

Other
Materials
9:50–10:35

Kneissl
11:00

UV LEDs I
11:35–12:35

Characteri-
zation
Challenges
11:35–12:35

Lunch
12:35–13:30

Excursion

Conference Dinner
19:00

Registration
8:00–9:00

Zhao
9:00–9:45

Manasevit
Award
9:45–10:15

Nov.Nitrides
10:20–10:50

BGaN
10:20–10:50

Coffee break 10:50–11:05

Oshiyama
11:05

Oxides and
Selenides
11:40–12:40

Theoretical
Approaches
and Rel.
11:40–12:40

Lunch
12:40–13:30

Poster session 2
13:30–15:30

Coffee break 15:30–15:45

Takeuchi
15:45

UV LEDs II
16:20–17:20

Photonic
Crystals
and Rel.
16:20–17:20

Closing
17:25